Technical Data Sheet



SPDT Ramses Low PIM N 12.4GHz Latching 12Vdc TTL Diodes Pins Terminals

PAGE 1/2 ISSUE 15.01.14 SERIE : SPDT PART NUMBER : R570132100LP

RF CHARACTERISTICS

Frequency range : 0 - 12.4 GHz Impedance : 50 Ohms

Frequency (GHz)	DC - 1	1 - 2	2 - 3	3 - 8	8 - 12.4
VSWR max	1.15	1.20	1.25	1.35	1.50
Insertion loss max	0.15 dB	0.20 dB	0.25 dB	0.35 dB	0.50 dB
Isolation min	85 dB	80 dB	75 dB	70 dB	60 dB
Average power (*)	700 W	500 W	400 W	250 W	200 W

	Passive intermodulation		
Tone 1	1810 MHz, approximately 43 dBm		
Tone 2	1850 MHz, approximately 43 dBm		
3 rd order PIM	- 160 dBc at 1770 MHz		

Depending on application, carrier powers and frequencies, PIM measurements can vary. PIM testing is not measured during product acceptance test.

ELECTRICAL CHARACTERISTICS

Actuator : LATCHING
Nominal current ** : 320 mA

Actuator voltage (Vcc) : 12V (10.2 to 13V)

Terminals : solder pins (250°C max. / 30 sec.)

TTL inputs (E) - High level : 2.2 to 5.5 V / 800µA at 5.5 V

- Low level : 0 to 0.8 V / 20µA at 0.8 V

MECHANICAL CHARACTERISTICS

Connectors : N female per MIL-C 39012

Life : 2 million cycles

Switching Time*** : < 15 ms

Construction : Splashproof

Weight : < 185 g

ENVIRONMENTAL CHARACTERISTICS

Operating temperature range : -25°C to +70°C
Storage temperature range : -55°C to +85°C

(* Average power at 25°C per RF Path)

(** At 25° C ±10%)

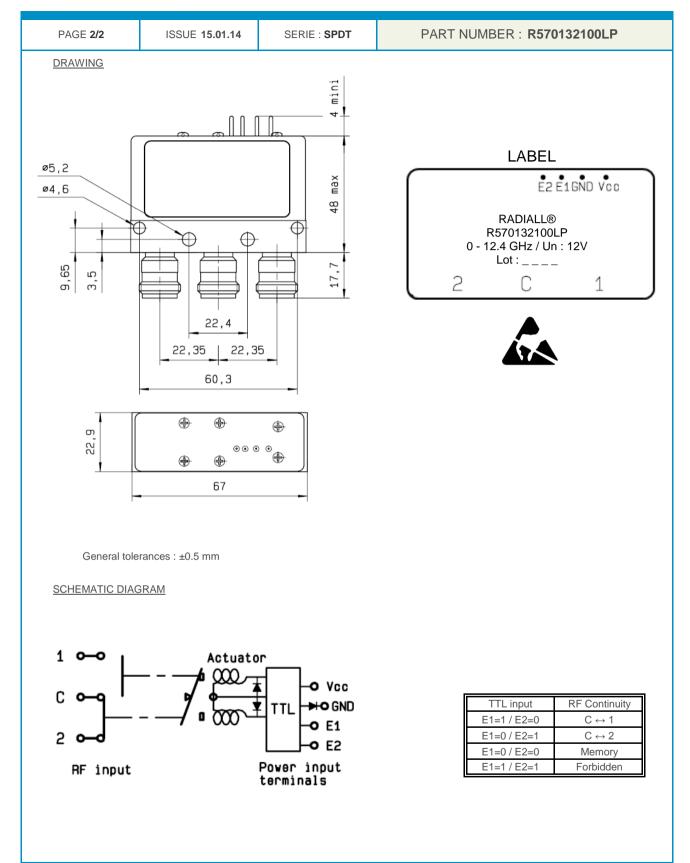
(*** Nominal voltage; 25° C)



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